

*Parameters Subject to Change Without Notice*

### DESCRIPTION

The JW<sup>®</sup>1962AH/JW1962BH(JW1962XH series) is a constant voltage controller with high voltage accuracy which applies to single stage boost power factor corrected(PFC) applications. The constant on time control strategy ensures high power factor, and the input voltage detection circuit is not needed, which simplifies the system design and saves the loss.

The critical conduction mode operation reduces the switching losses, improves the EMI performance and increases the efficiency.

JW1962XH series has multi-protection functions which largely enhance the safety and reliability of the system, including VCC UVLO, ISP over voltage protection, open feedback protection, FB over voltage protection and over-temperature protection.

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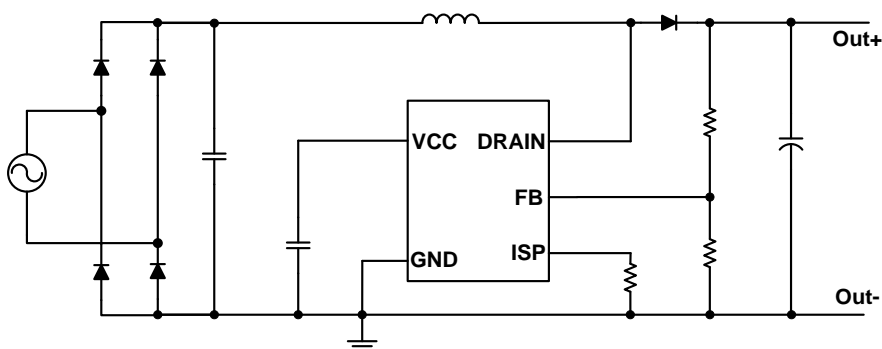
### FEATURES

- Low quiescent current
- High power factor and low THD
- Critical conduction mode
- High voltage power MOSFET integrated
- High reference voltage accuracy
- High efficiency over wide operating range
- Open feedback protection
- Disable function
- Pulse by pulse current limit
- FB over voltage protection
- ISP over voltage protection
- Internal over-temperature protection
- SOP8 package

### APPLICATIONS

- SMPS
- AC-DC adapter
- Flat TV

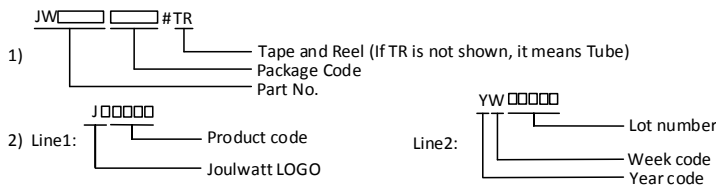
### TYPICAL APPLICATION



**ORDER INFORMATION**

DEVICE <sup>1)</sup>	PACKAGE	TOP MARKING <sup>2)</sup>	ENVIRONMENTAL <sup>3)</sup>
JW1962AHSOPB#TR	SOP8	J1962AH YW□□□□□	Green
JW1962BHSOPB#TR	SOP8	J1962BH YW□□□□□	Green

**Notes:**

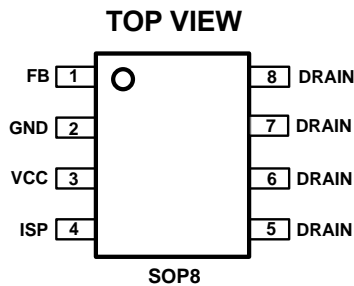


3) All Joulwatt products are packaged with Pb-free and Halogen-free materials and compliant to RoHS standards.

**DEVICE INFORMATION**

DEVICE	MOS RDSON
JW1962AHSOPB#TR	2.8Ω
JW1962BHSOPB#TR	1.8Ω

**PIN CONFIGURATION**



**ABSOLUTE MAXIMUM RATING<sup>1)</sup>**

VCC Current .....	7mA
DRAIN Voltage.....	500V
All Other Pins.....	.5 V
Junction Temperature <sup>2) 3)</sup> .....	150°C
Lead Temperature.....	260°C
Storage Temperature.....	-65°C to +150°C

**RECOMMENDED OPERATING CONDITIONS**

DRAIN Voltage.....30V~400V  
Operating Junction Temperature (T<sub>J</sub>)..... -40°C to 125°C

**THERMAL PERFORMANCE<sup>4)</sup>** $\theta_{JA}$      $\theta_{JC}$ 

SOP8.....96.....54°C/W

**Note:**

- 1) Exceeding these ratings may damage the device. These stress ratings do not imply function operation of the device at any other conditions beyond those indicated under RECOMMENDED OPERATING CONDITIONS.
- 2) The JW1962XH includes thermal protection that is intended to protect the device in overload conditions. Continuous operation over the specified absolute maximum operating junction temperature may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.

**ELECTRICAL CHARACTERISTICS**

*T<sub>A</sub>=25 °C, unless otherwise stated.*

Item	Symbol	Condition	Min.	Typ.	Max.	Units
<b>Power Supply</b>						
VCC Start-Up Voltage	V <sub>CC_ST</sub>			14.2		V
VCC Under Voltage Lockout	V <sub>CC_UVLO</sub>			8.2		V
VCC Operational Current at Disable	I <sub>VCC_DIS</sub>			44		µA
VCC Startup Supply Current	I <sub>VCC_ST</sub>	V <sub>CC</sub> = V <sub>CC_ST</sub> -0.2V		19	60	µA
VCC Over Voltage Threshold <sup>5)</sup>	V <sub>CC_OVP</sub>			23.2		V
VCC Shunt Current <sup>5)</sup>	I <sub>SHUNT</sub>	V <sub>CC</sub> =25V		10		mA
<b>Voltage Regulation</b>						
ISP Clamp Voltage	V <sub>ISP_MAX</sub>			0.5		V
FB Reference Voltage	V <sub>FB_REF</sub>		2.45	2.5	2.55	V
FB Start-up Voltage	V <sub>FB_ST</sub>			0.4		V
FB Quick Start-up Voltage	V <sub>FB_QST</sub>			2.1		V
FB Quick Start-up Hysteresis	V <sub>FB_QST_HYST</sub>			0.1		V
Maximum On Time of MOSFET	T <sub>ON_MAX</sub>			36		µs
Minimum On Time of MOSFET <sup>5)</sup>	T <sub>ON_MIN</sub>		0.36	0.42		µs
Maximum Off Time of MOSFET	T <sub>OFF_MAX</sub>			400		µs
Minimum Off Time of MOSFET <sup>5)</sup>	T <sub>OFF_MIN</sub>		0.6	0.85		µs
Maximum Switching Frequency	F <sub>MAX</sub>			300		kHz
<b>MOS</b>						
MOS Rdson <sup>5)</sup>	JW1962AH	Rdson	Vgs=10V		2.8	Ω
	JW1962BH				1.8	
Breakdown Voltage	BV	Vgs=10V	500			V
<b>Protection</b>						
ISP OVP Threshold	V <sub>ISP_OVP</sub>			1.5		V
OVP Threshold at FB Pin	V <sub>FB_OVP</sub>			2.7		V
FB OVP Hysteresis	V <sub>FB_OVP_HYST</sub>			0.2		V
Over Thermal Protection Threshold <sup>5)</sup>	T <sub>OTP</sub>			140		°C
Over Thermal Protection Hysteresis <sup>5)</sup>	T <sub>OTP_HYST</sub>			30		°C

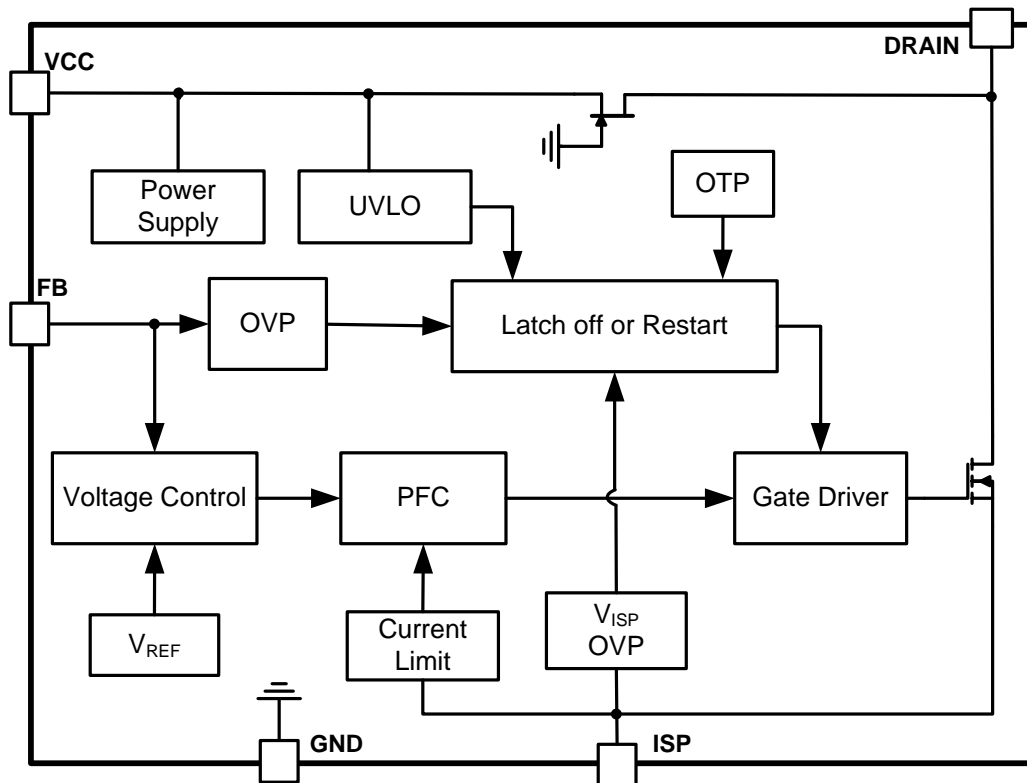
**Note:**

5) Guaranteed by design.

PIN DESCRIPTION

Pin No.	Name	Description
1	FB	Output voltage feedback pin.
2	GND	Chip ground.
3	VCC	Power supply.
4	ISP	Current detection pin.
5,6,7,8	DRAIN	Drain of the power MOS.

BLOCK DIAGRAM



## FUNCTIONAL DESCRIPTION

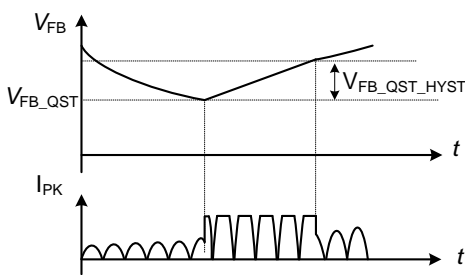
The JW1962XH series is a constant voltage(CV) regulator which applies to boost system with power factor correction. JW1962XH series can achieve excellent line and load regulations, high efficiency and low system cost with few peripheral components.

### Start Up

When VCC is charged to VCC Start-Up Voltage(V<sub>CC\_ST</sub>), the GATE driver begins to switch. When VCC is higher than VCC Over Voltage Threshold(V<sub>CC\_OVP</sub>), VCC shunt current is enabled to prevent VCC from being too high. When VCC is lower than VCC under voltage lockout(V<sub>CC\_UVLO</sub>), the chip stops switching.

### Quick Start up Function

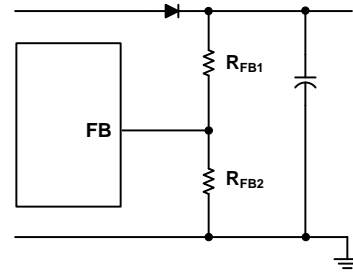
JW1962XH series enters into quick start up mode when V<sub>FB</sub> is lower than FB Quick Start up Voltage(V<sub>FB\_QST</sub>). I<sub>PK</sub> is I<sub>PK\_MAX</sub> unless T<sub>ON</sub> reaches Maximum ON Time(T<sub>ON\_MAX</sub>), which accelerates the start up process and decreases the voltage drop in light to heavy load transient. JW1962XH series quits this mode when V<sub>FB</sub> is larger than V<sub>FB\_QST</sub>+ V<sub>FB\_QST\_HYST</sub>.



### Constant Voltage Control

The JW1962XH series controls the output voltage from the information of FB pin. The output voltage is

$$V_O = V_{FB\_REF} \times (R_{FB1} + R_{FB2}) / R_{FB2}$$



Where

V<sub>FB\_REF</sub> – The FB Reference Voltage;  
R<sub>FB1</sub>, R<sub>FB2</sub> – FB divide resistors.

### Critical Conduction Mode Operation

JW1962XH series works in the critical conduction mode of the inductor current. When the power MOSFET is turned on, the inductor current increases from zero. The turn on time of the MOSFET can be calculated as:

$$T_{ON} = I_{PK} \times L / V_{IN}$$

Where,

L – Inductance;  
V<sub>IN</sub> – Input voltage.

I<sub>PK</sub> is the peak current in one switching period and the maximum value(I<sub>PK\_MAX</sub>) is limited by the MOS current sensing resistor(R<sub>ISP</sub>).

$$I_{PK\_MAX} = V_{ISP\_MAX} / R_{ISP}$$

V<sub>ISP\_MAX</sub> – ISP Clamp Voltage.

When the power MOSFET is turned off, the inductor current begins to decrease. The power MOSFET turns on again when the inductor current is zero. The turn off time of the MOSFET can be calculated as:

$$T_{OFF} = I_{PK} \times L / (V_{OUT} - V_{IN})$$

Where,

V<sub>OUT</sub> – Output voltage.

The power inductance can be calculated as:

$$L = V_{IN} \times (V_{OUT} - V_{IN}) / (f \times I_{PK} \times V_{OUT})$$

Where, f is the switching frequency of the boost system.

### Disable Function

The FB pin can also be used for device disabling.

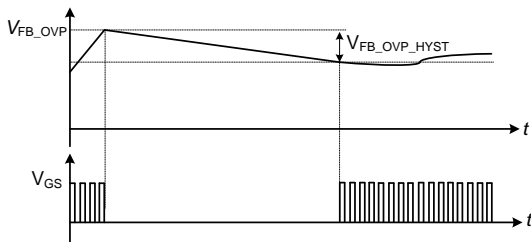
If  $V_{FB}$  is pulled down and lower than FB start up voltage( $V_{FB\_ST}$ ), JW1962XH series stops switching and enters in green mode which reduces the power consumption. JW1962XH series will restart if  $V_{FB} > V_{FB\_ST}$ .

**ISP Over Voltage Protection**

Normally the Maximum  $V_{ISP}$  is clamped to  $V_{ISP\_MAX}$ , but  $V_{ISP}$  is very high if the inductor or the freewheeling diode is shorted. When  $V_{ISP}$  is higher than ISP OVP threshold( $V_{ISP\_OVP}$ ), ISP over voltage protection is triggered and JW1962XH series stops switching for 800mS.

**FB Over Voltage Protection**

The over voltage protection is triggered if  $V_{FB}$  is over than FB over voltage protection threshold( $V_{FB\_OVP}$ ). The internal comp will be reset and the power MOSFET gate driver stops switching unless FB voltage is decreased to  $V_{FB\_OVP} - V_{FB\_OVP\_HYST}$ .



**Over Temperature Protection**

When internal temperature of the chip exceeds the Over Thermal Protection Threshold( $T_{OTP}$ ), JW1962XH series stops switching unless the junction temperature is decreased to  $T_{OTP} - T_{OTP\_HYST}$ .

**PCB Design**

When designing the PCB system, please follow the directions :

1. The VCC pin must be locally bypassed with a capacitor.
2. Make the area of the power loop as small as possible in order to reduce the EMI radiation.

REFERENCE DESIGN

This reference design is suitable for 40W PFC, using JW1962BH, with high efficiency, excellent load regulation.

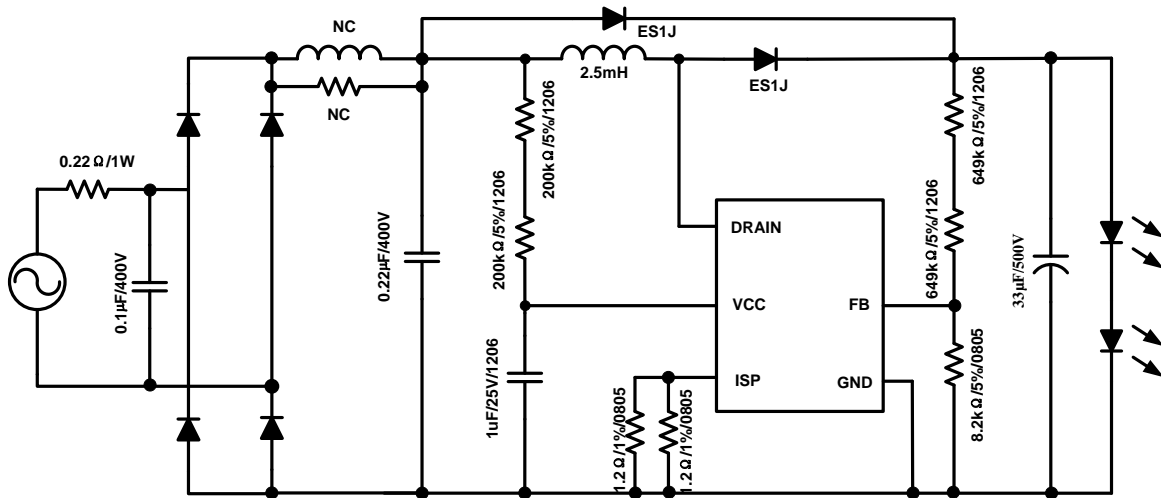
Reference :

V<sub>IN</sub>: 180VAC~264VAC

V<sub>OUT</sub>: 400V

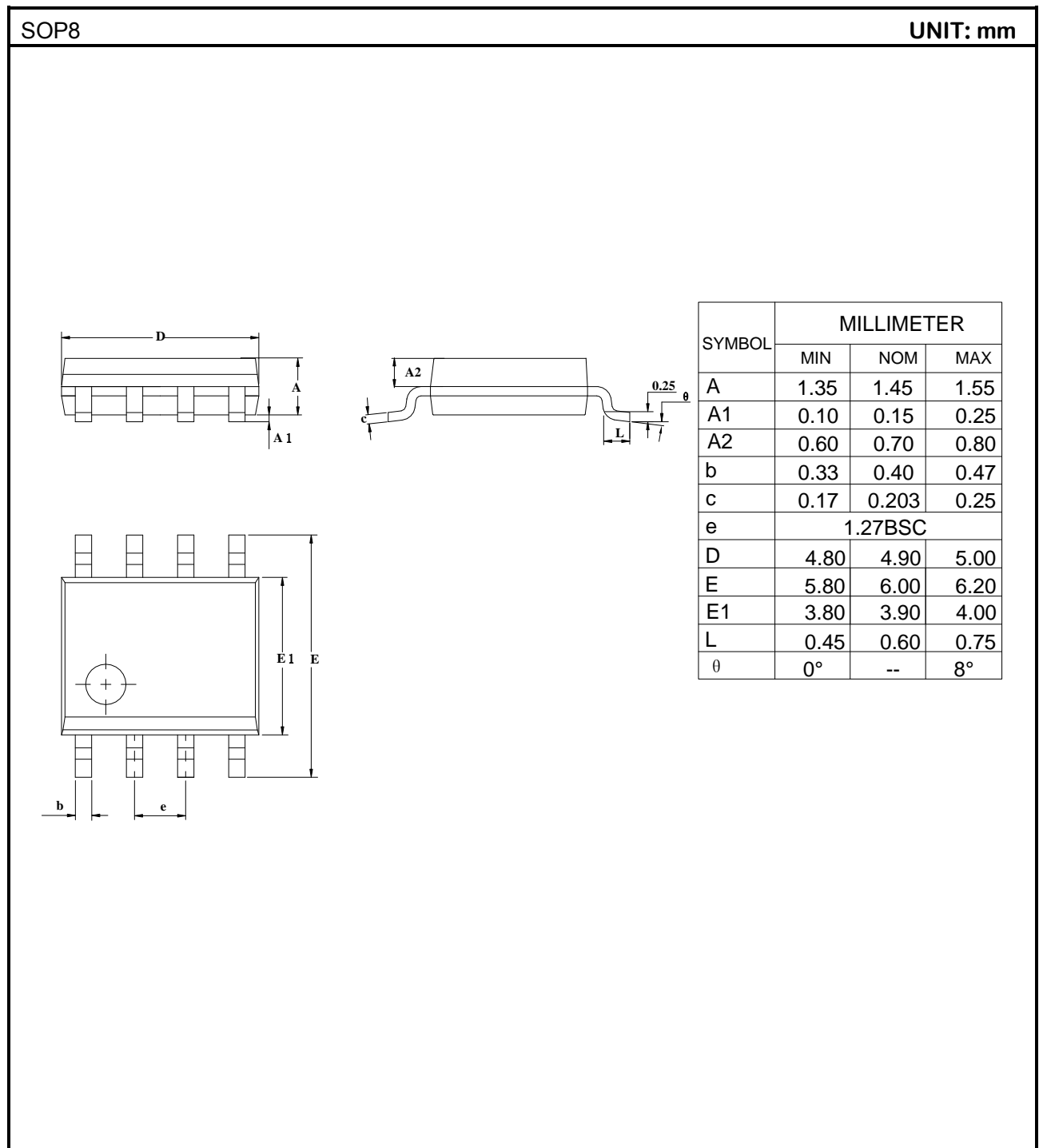
Maximum I<sub>OUT</sub>: 90mA

PF: >0.9





PACKAGE OUTLINE



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